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Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Not For New Designs
Core Processor	R8C
Core Size	16-Bit
Speed	20MHz
Connectivity	I ² C, LINbus, SIO, SSU, UART/USART
Peripherals	POR, PWM, Voltage Detect, WDT
Number of I/O	15
Program Memory Size	16KB (16K x 8)
Program Memory Type	FLASH
EEPROM Size	4K x 8
RAM Size	1.5K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 5.5V
Data Converters	A/D 4x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	20-LSSOP (0.173", 4.40mm Width)
Supplier Device Package	20-LSSOP
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f21324cdsp-u0

1.2 Product List

Table 1.3 lists Product List for R8C/32C Group, and Figure 1.1 shows a Part Number, Memory Size, and Package of R8C/32C Group.

Table 1.3 Product List for R8C/32C Group **Current of Aug 2010**

Part No.	ROM Capacity		RAM Capacity	Package Type	Remarks
	Program ROM	Data flash			
R5F21321CNSP	4 Kbytes	1 Kbyte × 4	512 bytes	PLSP0020JB-A	N version
R5F21322CNSP	8 Kbytes	1 Kbyte × 4	1 Kbyte	PLSP0020JB-A	
R5F21324CNSP	16 Kbytes	1 Kbyte × 4	1.5 Kbytes	PLSP0020JB-A	
R5F21321CDSP	4 Kbytes	1 Kbyte × 4	512 bytes	PLSP0020JB-A	D version
R5F21322CDSP	8 Kbytes	1 Kbyte × 4	1 Kbyte	PLSP0020JB-A	
R5F21324CDSP	16 Kbytes	1 Kbyte × 4	1.5 Kbytes	PLSP0020JB-A	

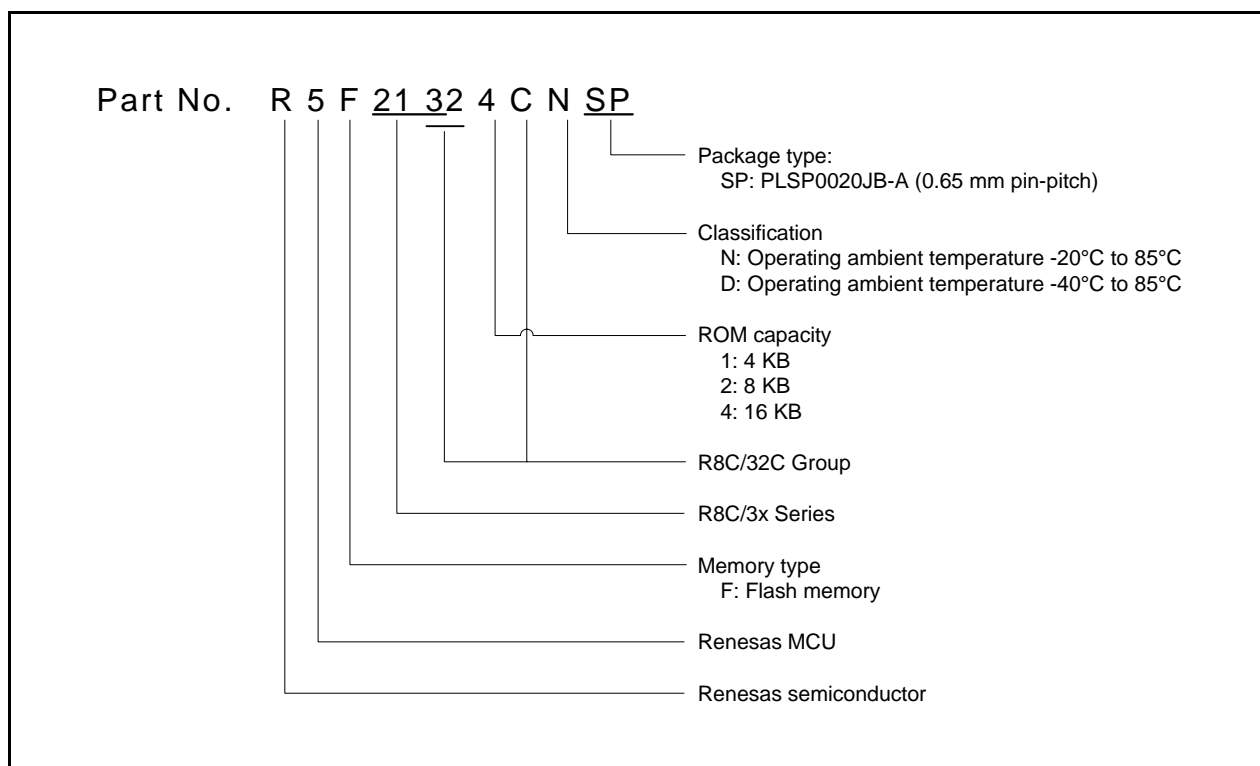


Figure 1.1 Part Number, Memory Size, and Package of R8C/32C Group

3. Memory

3.1 R8C/32C Group

Figure 3.1 is a Memory Map of R8C/32C Group. The R8C/32C Group has a 1-Mbyte address space from addresses 00000h to FFFFFh. The internal ROM (program ROM) is allocated lower addresses, beginning with address 0FFFFh. For example, a 16-Kbyte internal ROM area is allocated addresses 0C000h to 0FFFFh.

The fixed interrupt vector table is allocated addresses 0FFDCh to 0FFFFh. The starting address of each interrupt routine is stored here.

The internal ROM (data flash) is allocated addresses 03000h to 03FFFh.

The internal RAM is allocated higher addresses, beginning with address 00400h. For example, a 1.5-Kbyte internal RAM area is allocated addresses 00400h to 009FFh. The internal RAM is used not only for data storage but also as a stack area when a subroutine is called or when an interrupt request is acknowledged.

Special function registers (SFRs) are allocated addresses 00000h to 002FFh and 02C00h to 02FFFh. Peripheral function control registers are allocated here. All unallocated spaces within the SFRs are reserved and cannot be accessed by users.

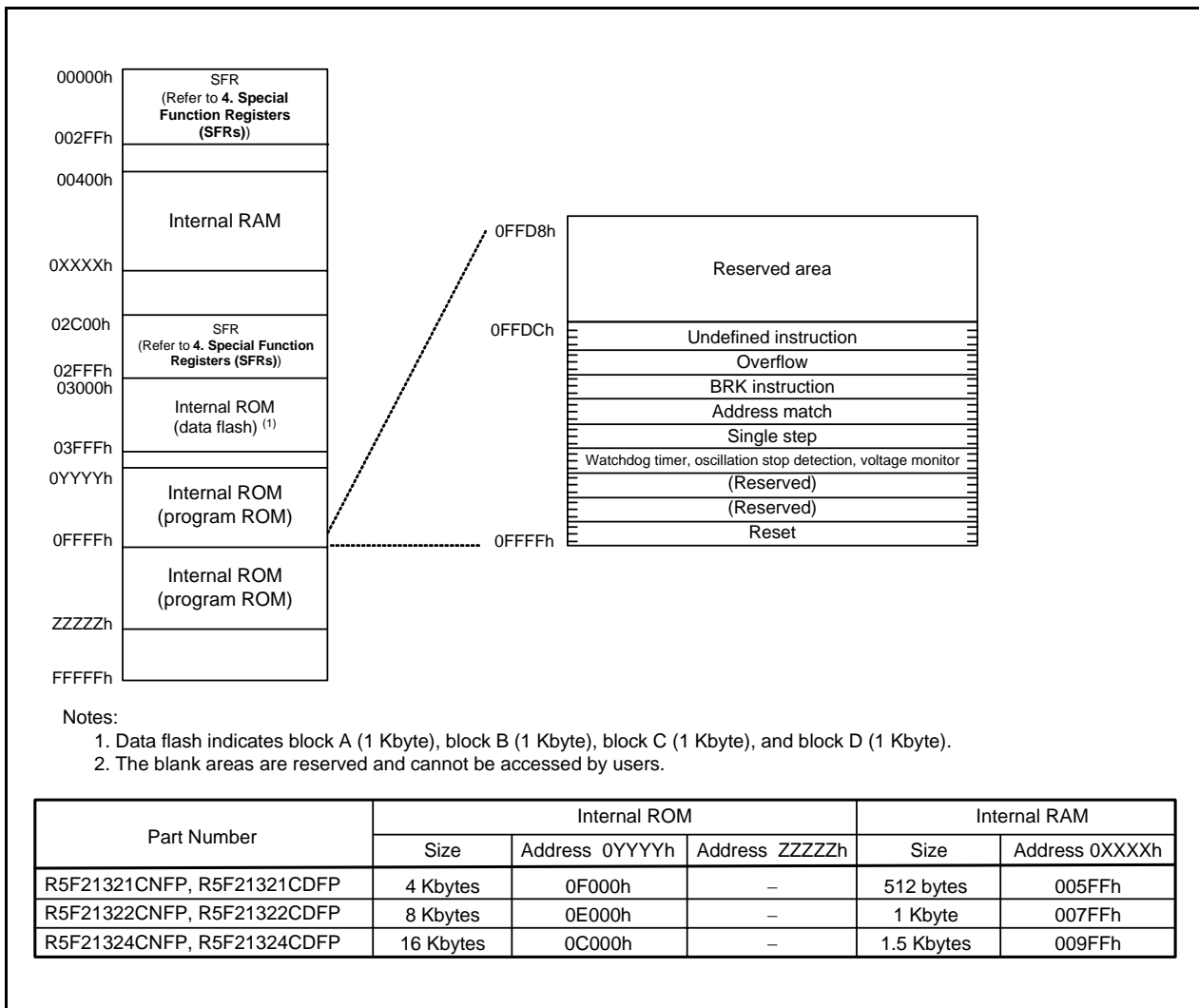


Figure 3.1 Memory Map of R8C/32C Group

Table 4.2 SFR Information (2) (1)

Address	Register	Symbol	After Reset
003Ah	Voltage Monitor 2 Circuit Control Register	VW2C	1000010b
003Bh			
003Ch			
003Dh			
003Eh			
003Fh			
0040h			
0041h	Flash Memory Ready Interrupt Control Register	FMRDYIC	XXXXX000b
0042h			
0043h			
0044h			
0045h			
0046h			
0047h	Timer RC Interrupt Control Register	TRCIC	XXXXX000b
0048h			
0049h			
004Ah	Timer RE Interrupt Control Register	TREIC	XXXXX000b
004Bh	UART2 Transmit Interrupt Control Register	S2TIC	XXXXX000b
004Ch	UART2 Receive Interrupt Control Register	S2RIC	XXXXX000b
004Dh	Key Input Interrupt Control Register	KUPIC	XXXXX000b
004Eh	A/D Conversion Interrupt Control Register	ADIC	XXXXX000b
004Fh	SSU Interrupt Control Register / IIC bus Interrupt Control Register (2)	SSUIC / IICIC	XXXXX000b
0050h			
0051h	UART0 Transmit Interrupt Control Register	S0TIC	XXXXX000b
0052h	UART0 Receive Interrupt Control Register	S0RIC	XXXXX000b
0053h			
0054h			
0055h			
0056h	Timer RA Interrupt Control Register	TRAIC	XXXXX000b
0057h			
0058h	Timer RB Interrupt Control Register	TRBIC	XXXXX000b
0059h	INT1 Interrupt Control Register	INT1IC	XX00X000b
005Ah	INT3 Interrupt Control Register	INT3IC	XX00X000b
005Bh			
005Ch			
005Dh	INT0 Interrupt Control Register	INT0IC	XX00X000b
005Eh	UART2 Bus Collision Detection Interrupt Control Register	U2BCNIC	XXXXX000b
005Fh			
0060h			
0061h			
0062h			
0063h			
0064h			
0065h			
0066h			
0067h			
0068h			
0069h			
006Ah			
006Bh			
006Ch			
006Dh			
006Eh			
006Fh			
0070h			
0071h			
0072h	Voltage Monitor 1 Interrupt Control Register	VCMP1IC	XXXXX000b
0073h	Voltage Monitor 2 Interrupt Control Register	VCMP2IC	XXXXX000b
0074h			
0075h			
0076h			
0077h			
0078h			
0079h			
007Ah			
007Bh			
007Ch			
007Dh			
007Eh			
007Fh			

X: Undefined

Notes:

1. The blank areas are reserved and cannot be accessed by users.
2. Selectable by the IICSEL bit in the SSUICSR register.

Table 4.8 SFR Information (8) (1)

Address	Register	Symbol	After Reset
01C0h	Address Match Interrupt Register 0	RMAD0	XXh
01C1h			XXh
01C2h			0000XXXXb
01C3h	Address Match Interrupt Enable Register 0	AIER0	00h
01C4h			XXh
01C5h	Address Match Interrupt Register 1	RMAD1	XXh
01C6h			XXh
01C7h			0000XXXXb
01C8h	Address Match Interrupt Enable Register 1	AIER1	00h
01C9h			
01CAh			
01CBh			
01CCh			
01CDh			
01CEh			
01CFh			
01D0h			
01D1h			
01D2h			
01D3h			
01D4h			
01D5h			
01D6h			
01D7h			
01D8h			
01D9h			
01DAh			
01DBh			
01DCh			
01DDh			
01DEh			
01DFh			
01E0h	Pull-Up Control Register 0	PUR0	00h
01E1h	Pull-Up Control Register 1	PUR1	00h
01E2h			
01E3h			
01E4h			
01E5h			
01E6h			
01E7h			
01E8h			
01E9h			
01EAh			
01EBh			
01ECh			
01EDh			
01EEh			
01EFh			
01F0h	Port P1 Drive Capacity Control Register	P1DRR	00h
01F1h			
01F2h	Drive Capacity Control Register 0	DRR0	00h
01F3h	Drive Capacity Control Register 1	DRR1	00h
01F4h			
01F5h	Input Threshold Control Register 0	VLT0	00h
01F6h	Input Threshold Control Register 1	VLT1	00h
01F7h			
01F8h	Comparator B Control Register 0	INTCMP	00h
01F9h			
01FAh	External Input Enable Register 0	INTEN	00h
01FBh			
01FCh	INT Input Filter Select Register 0	INTF	00h
01FDh			
01FEh	Key Input Enable Register 0	KIEN	00h
01FFh			

X: Undefined

Note:

1. The blank areas are reserved and cannot be accessed by users.

Table 4.9 SFR Information (9) (1)

Address	Register	Symbol	After Reset
2C00h	DTC Transfer Vector Area		XXh
2C01h	DTC Transfer Vector Area		XXh
2C02h	DTC Transfer Vector Area		XXh
2C03h	DTC Transfer Vector Area		XXh
2C04h	DTC Transfer Vector Area		XXh
2C05h	DTC Transfer Vector Area		XXh
2C06h	DTC Transfer Vector Area		XXh
2C07h	DTC Transfer Vector Area		XXh
2C08h	DTC Transfer Vector Area		XXh
2C09h	DTC Transfer Vector Area		XXh
2C0Ah	DTC Transfer Vector Area		XXh
:	DTC Transfer Vector Area		XXh
:	DTC Transfer Vector Area		XXh
2C3Ah	DTC Transfer Vector Area		XXh
2C3Bh	DTC Transfer Vector Area		XXh
2C3Ch	DTC Transfer Vector Area		XXh
2C3Dh	DTC Transfer Vector Area		XXh
2C3Eh	DTC Transfer Vector Area		XXh
2C3Fh	DTC Transfer Vector Area		XXh
2C40h	DTC Control Data 0	DTCD0	XXh
2C41h			XXh
2C42h			XXh
2C43h			XXh
2C44h			XXh
2C45h			XXh
2C46h			XXh
2C47h			XXh
2C48h	DTC Control Data 1	DTCD1	XXh
2C49h			XXh
2C4Ah			XXh
2C4Bh			XXh
2C4Ch			XXh
2C4Dh			XXh
2C4Eh			XXh
2C4Fh			XXh
2C50h	DTC Control Data 2	DTCD2	XXh
2C51h			XXh
2C52h			XXh
2C53h			XXh
2C54h			XXh
2C55h			XXh
2C56h			XXh
2C57h			XXh
2C58h	DTC Control Data 3	DTCD3	XXh
2C59h			XXh
2C5Ah			XXh
2C5Bh			XXh
2C5Ch			XXh
2C5Dh			XXh
2C5Eh			XXh
2C5Fh			XXh
2C60h	DTC Control Data 4	DTCD4	XXh
2C61h			XXh
2C62h			XXh
2C63h			XXh
2C64h			XXh
2C65h			XXh
2C66h			XXh
2C67h			XXh
2C68h	DTC Control Data 5	DTCD5	XXh
2C69h			XXh
2C6Ah			XXh
2C6Bh			XXh
2C6Ch			XXh
2C6Dh			XXh
2C6Eh			XXh
2C6Fh			XXh

X: Undefined

Note:

1. The blank areas are reserved and cannot be accessed by users.

Table 4.10 SFR Information (10) (1)

Address	Register	Symbol	After Reset
2C70h	DTC Control Data 6	DTCD6	XXh
2C71h			XXh
2C72h			XXh
2C73h			XXh
2C74h			XXh
2C75h			XXh
2C76h			XXh
2C77h			XXh
2C78h	DTC Control Data 7	DTCD7	XXh
2C79h			XXh
2C7Ah			XXh
2C7Bh			XXh
2C7Ch			XXh
2C7Dh			XXh
2C7Eh			XXh
2C7Fh			XXh
2C80h	DTC Control Data 8	DTCD8	XXh
2C81h			XXh
2C82h			XXh
2C83h			XXh
2C84h			XXh
2C85h			XXh
2C86h			XXh
2C87h			XXh
2C88h	DTC Control Data 9	DTCD9	XXh
2C89h			XXh
2C8Ah			XXh
2C8Bh			XXh
2C8Ch			XXh
2C8Dh			XXh
2C8Eh			XXh
2C8Fh			XXh
2C90h	DTC Control Data 10	DTCD10	XXh
2C91h			XXh
2C92h			XXh
2C93h			XXh
2C94h			XXh
2C95h			XXh
2C96h			XXh
2C97h			XXh
2C98h	DTC Control Data 11	DTCD11	XXh
2C99h			XXh
2C9Ah			XXh
2C9Bh			XXh
2C9Ch			XXh
2C9Dh			XXh
2C9Eh			XXh
2C9Fh			XXh
2CA0h	DTC Control Data 12	DTCD12	XXh
2CA1h			XXh
2CA2h			XXh
2CA3h			XXh
2CA4h			XXh
2CA5h			XXh
2CA6h			XXh
2CA7h			XXh
2CA8h	DTC Control Data 13	DTCD13	XXh
2CA9h			XXh
2CAAh			XXh
2CABh			XXh
2CACH			XXh
2CADh			XXh
2CAEh			XXh
2CAFh			XXh

X: Undefined

Note:

1. The blank areas are reserved and cannot be accessed by users.

5. Electrical Characteristics

Table 5.1 Absolute Maximum Ratings

Symbol	Parameter	Condition	Rated Value	Unit
V _{CC} /AV _{CC}	Supply voltage		-0.3 to 6.5	V
V _I	Input voltage		-0.3 to V _{CC} + 0.3	V
V _O	Output voltage		-0.3 to V _{CC} + 0.3	V
P _d	Power dissipation	-40°C ≤ T _{opr} ≤ 85°C	500	mW
T _{opr}	Operating ambient temperature		-20 to 85 (N version) / -40 to 85 (D version)	°C
T _{stg}	Storage temperature		-65 to 150	°C

Table 5.2 Recommended Operating Conditions

Symbol	Parameter		Conditions	Standard			Unit		
				Min.	Typ.	Max.			
V _{CC} /AV _{CC}	Supply voltage			1.8	–	5.5	V		
V _{SS} /AV _{SS}	Supply voltage			–	0	–	V		
V _{IH}	Input “H” voltage	Other than CMOS input			0.8 V _{CC}	–	V _{CC}	V	
		CMOS input	Input level switching function (I/O port)	Input level selection : 0.35 V _{CC}	4.0 V ≤ V _{CC} ≤ 5.5 V	0.5 V _{CC}	–	V _{CC}	V
					2.7 V ≤ V _{CC} < 4.0 V	0.55 V _{CC}	–	V _{CC}	V
					1.8 V ≤ V _{CC} < 2.7 V	0.65 V _{CC}	–	V _{CC}	V
			Input level selection : 0.5 V _{CC}		4.0 V ≤ V _{CC} ≤ 5.5 V	0.65 V _{CC}	–	V _{CC}	V
				2.7 V ≤ V _{CC} < 4.0 V	0.7 V _{CC}	–	V _{CC}	V	
				1.8 V ≤ V _{CC} < 2.7 V	0.8 V _{CC}	–	V _{CC}	V	
			Input level selection : 0.7 V _{CC}		4.0 V ≤ V _{CC} ≤ 5.5 V	0.85 V _{CC}	–	V _{CC}	V
				2.7 V ≤ V _{CC} < 4.0 V	0.85 V _{CC}	–	V _{CC}	V	
				1.8 V ≤ V _{CC} < 2.7 V	0.85 V _{CC}	–	V _{CC}	V	
		External clock input (XOUT)			1.2	–	V _{CC}	V	
V _{IL}	Input “L” voltage	Other than CMOS input			0	–	0.2 V _{CC}	V	
		CMOS input	Input level switching function (I/O port)	Input level selection : 0.35 V _{CC}	4.0 V ≤ V _{CC} ≤ 5.5 V	0	–	0.2 V _{CC}	V
					2.7 V ≤ V _{CC} < 4.0 V	0	–	0.2 V _{CC}	V
					1.8 V ≤ V _{CC} < 2.7 V	0	–	0.2 V _{CC}	V
			Input level selection : 0.5 V _{CC}		4.0 V ≤ V _{CC} ≤ 5.5 V	0	–	0.4 V _{CC}	V
				2.7 V ≤ V _{CC} < 4.0 V	0	–	0.3 V _{CC}	V	
				1.8 V ≤ V _{CC} < 2.7 V	0	–	0.2 V _{CC}	V	
			Input level selection : 0.7 V _{CC}		4.0 V ≤ V _{CC} ≤ 5.5 V	0	–	0.55 V _{CC}	V
				2.7 V ≤ V _{CC} < 4.0 V	0	–	0.45 V _{CC}	V	
				1.8 V ≤ V _{CC} < 2.7 V	0	–	0.35 V _{CC}	V	
	External clock input (XOUT)			0	–	0.4	V		
I _{OH(sum)}	Peak sum output “H” current	Sum of all pins I _{OH(peak)}			–	–	–160	mA	
I _{OH(sum)}	Average sum output “H” current	Sum of all pins I _{OH(avg)}			–	–	–80	mA	
I _{OH(peak)}	Peak output “H” current	Drive capacity Low			–	–	–10	mA	
		Drive capacity High			–	–	–40	mA	
I _{OH(avg)}	Average output “H” current	Drive capacity Low			–	–	–5	mA	
		Drive capacity High			–	–	–20	mA	
I _{OL(sum)}	Peak sum output “L” current	Sum of all pins I _{OL(peak)}			–	–	160	mA	
I _{OL(sum)}	Average sum output “L” current	Sum of all pins I _{OL(avg)}			–	–	80	mA	
I _{OL(peak)}	Peak output “L” current	Drive capacity Low			–	–	10	mA	
		Drive capacity High			–	–	40	mA	
I _{OL(avg)}	Average output “L” current	Drive capacity Low			–	–	5	mA	
		Drive capacity High			–	–	20	mA	
f _(XIN)	XIN clock input oscillation frequency	2.7 V ≤ V _{CC} ≤ 5.5 V			–	–	20	MHz	
		1.8 V ≤ V _{CC} < 2.7 V			–	–	5	MHz	
f _(XCIN)	XCIN clock input oscillation frequency	1.8 V ≤ V _{CC} ≤ 5.5 V			–	32.768	50	kHz	
f _{OCO40M}	When used as the count source for timer RC ⁽³⁾	2.7 V ≤ V _{CC} ≤ 5.5 V			32	–	40	MHz	
f _{OCO-F}	f _{OCO-F} frequency	2.7 V ≤ V _{CC} ≤ 5.5 V			–	–	20	MHz	
		1.8 V ≤ V _{CC} < 2.7 V			–	–	5	MHz	
–	System clock frequency	2.7 V ≤ V _{CC} ≤ 5.5 V			–	–	20	MHz	
		1.8 V ≤ V _{CC} < 2.7 V			–	–	5	MHz	
f _(CLK)	CPU clock frequency	2.7 V ≤ V _{CC} ≤ 5.5 V			–	–	20	MHz	
		1.8 V ≤ V _{CC} < 2.7 V			–	–	5	MHz	

Notes:

1. V_{CC} = 1.8 to 5.5 V and T_{opr} = –20 to 85°C (N version) / –40 to 85°C (D version), unless otherwise specified.
2. The average output current indicates the average value of current measured during 100 ms.
3. f_{OCO40M} can be used as the count source for timer RC in the range of V_{CC} = 2.7 V to 5.5V.

Table 5.7 Voltage Detection 0 Circuit Electrical Characteristics

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
V _{det0}	Voltage detection level V _{det0_0} (2)		1.80	1.90	2.05	V
	Voltage detection level V _{det0_1} (2)		2.15	2.35	2.50	V
	Voltage detection level V _{det0_2} (2)		2.70	2.85	3.05	V
	Voltage detection level V _{det0_3} (2)		3.55	3.80	4.05	V
–	Voltage detection 0 circuit response time (4)	At the falling of V _{cc} from 5 V to (V _{det0_0} – 0.1) V	–	6	150	μs
–	Voltage detection circuit self power consumption	VCA25 = 1, V _{cc} = 5.0 V	–	1.5	–	μA
t _{d(E-A)}	Waiting time until voltage detection circuit operation starts (3)		–	–	100	μs

Notes:

1. The measurement condition is V_{cc} = 1.8 V to 5.5 V and T_{opr} = –20 to 85°C (N version) / –40 to 85°C (D version).
2. Select the voltage detection level with bits VDSEL0 and VDSEL1 in the OFS register.
3. Necessary time until the voltage detection circuit operates when setting to 1 again after setting the VCA25 bit in the VCA2 register to 0.
4. Time until the voltage monitor 0 reset is generated after the voltage passes V_{det0}.

Table 5.8 Voltage Detection 1 Circuit Electrical Characteristics

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
V _{det1}	Voltage detection level V _{det1_0} (2)	At the falling of V _{cc}	2.00	2.20	2.40	V
	Voltage detection level V _{det1_1} (2)	At the falling of V _{cc}	2.15	2.35	2.55	V
	Voltage detection level V _{det1_2} (2)	At the falling of V _{cc}	2.30	2.50	2.70	V
	Voltage detection level V _{det1_3} (2)	At the falling of V _{cc}	2.45	2.65	2.85	V
	Voltage detection level V _{det1_4} (2)	At the falling of V _{cc}	2.60	2.80	3.00	V
	Voltage detection level V _{det1_5} (2)	At the falling of V _{cc}	2.75	2.95	3.15	V
	Voltage detection level V _{det1_6} (2)	At the falling of V _{cc}	2.85	3.10	3.40	V
	Voltage detection level V _{det1_7} (2)	At the falling of V _{cc}	3.00	3.25	3.55	V
	Voltage detection level V _{det1_8} (2)	At the falling of V _{cc}	3.15	3.40	3.70	V
	Voltage detection level V _{det1_9} (2)	At the falling of V _{cc}	3.30	3.55	3.85	V
	Voltage detection level V _{det1_A} (2)	At the falling of V _{cc}	3.45	3.70	4.00	V
	Voltage detection level V _{det1_B} (2)	At the falling of V _{cc}	3.60	3.85	4.15	V
	Voltage detection level V _{det1_C} (2)	At the falling of V _{cc}	3.75	4.00	4.30	V
	Voltage detection level V _{det1_D} (2)	At the falling of V _{cc}	3.90	4.15	4.45	V
	Voltage detection level V _{det1_E} (2)	At the falling of V _{cc}	4.05	4.30	4.60	V
	Voltage detection level V _{det1_F} (2)	At the falling of V _{cc}	4.20	4.45	4.75	V
–	Hysteresis width at the rising of V _{cc} in voltage detection 1 circuit	V _{det1_0} to V _{det1_5} selected	–	0.07	–	V
		V _{det1_6} to V _{det1_F} selected	–	0.10	–	V
–	Voltage detection 1 circuit response time (3)	At the falling of V _{cc} from 5 V to (V _{det1_0} – 0.1) V	–	60	150	μs
–	Voltage detection circuit self power consumption	VCA26 = 1, V _{cc} = 5.0 V	–	1.7	–	μA
t _{d(E-A)}	Waiting time until voltage detection circuit operation starts (4)		–	–	100	μs

Notes:

1. The measurement condition is V_{cc} = 1.8 V to 5.5 V and T_{opr} = –20 to 85°C (N version) / –40 to 85°C (D version).
2. Select the voltage detection level with bits VD1S0 to VD1S3 in the VD1LS register.
3. Time until the voltage monitor 1 interrupt request is generated after the voltage passes V_{det1}.
4. Necessary time until the voltage detection circuit operates when setting to 1 again after setting the VCA26 bit in the VCA2 register to 0.

Table 5.9 Voltage Detection 2 Circuit Electrical Characteristics

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
V _{det2}	Voltage detection level V _{det2_0}	At the falling of V _{cc}	3.70	4.00	4.30	V
–	Hysteresis width at the rising of V _{cc} in voltage detection 2 circuit		–	0.10	–	V
–	Voltage detection 2 circuit response time ⁽²⁾	At the falling of V _{cc} from 5 V to (V _{det2_0} – 0.1) V	–	20	150	μs
–	Voltage detection circuit self power consumption	VCA27 = 1, V _{cc} = 5.0 V	–	1.7	–	μA
t _{d(E-A)}	Waiting time until voltage detection circuit operation starts ⁽³⁾		–	–	100	μs

Notes:

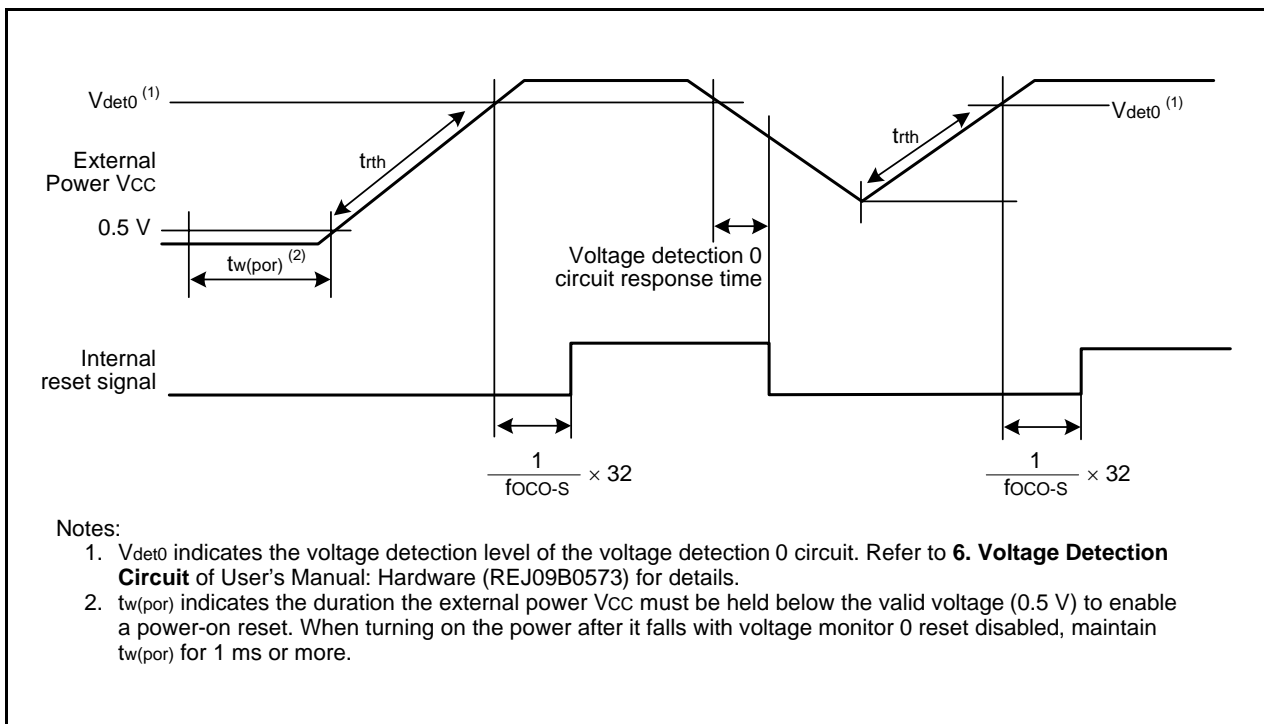
1. The measurement condition is V_{cc} = 1.8 V to 5.5 V and T_{opr} = –20 to 85°C (N version) / –40 to 85°C (D version).
2. Time until the voltage monitor 2 interrupt request is generated after the voltage passes V_{det2}.
3. Necessary time until the voltage detection circuit operates after setting to 1 again after setting the VCA27 bit in the VCA2 register to 0.

Table 5.10 Power-on Reset Circuit (2)

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
t _{rth}	External power V _{cc} rise gradient	⁽¹⁾	0	–	50,000	mV/msec

Notes:

1. The measurement condition is T_{opr} = –20 to 85°C (N version) / –40 to 85°C (D version), unless otherwise specified.
2. To use the power-on reset function, enable voltage monitor 0 reset by setting the LVDAS bit in the OFS register to 0.



Notes:

1. V_{det0} indicates the voltage detection level of the voltage detection 0 circuit. Refer to **6. Voltage Detection Circuit** of User's Manual: Hardware (REJ09B0573) for details.
2. t_{w(por)} indicates the duration the external power V_{cc} must be held below the valid voltage (0.5 V) to enable a power-on reset. When turning on the power after it falls with voltage monitor 0 reset disabled, maintain t_{w(por)} for 1 ms or more.

Figure 5.3 Power-on Reset Circuit Electrical Characteristics

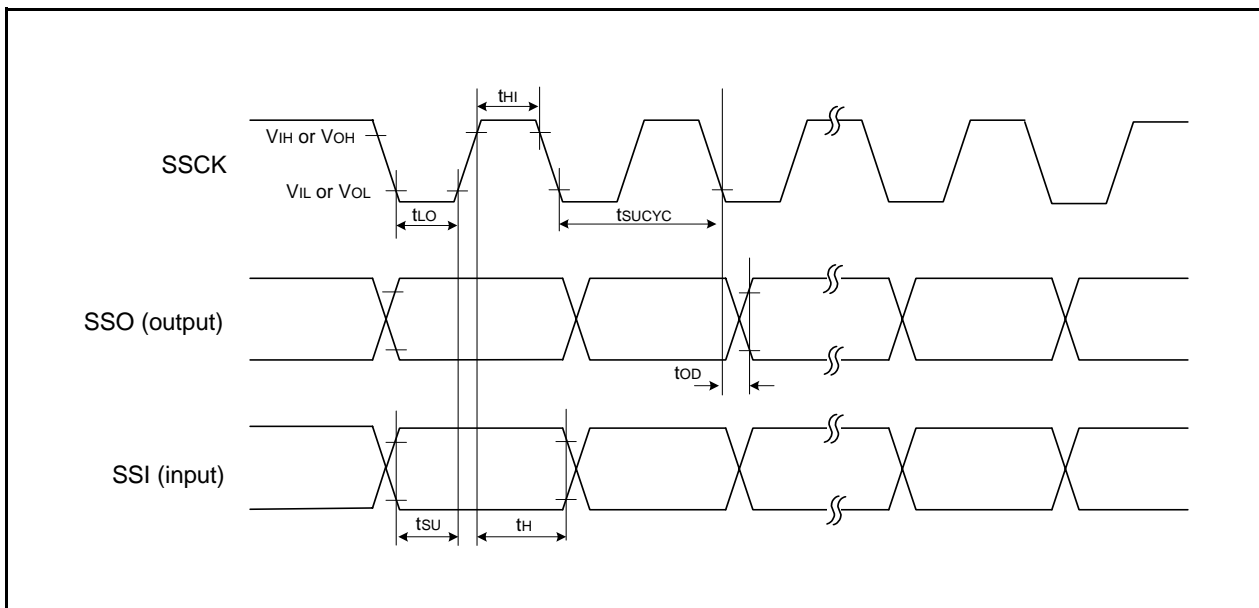


Figure 5.6 I/O Timing of Synchronous Serial Communication Unit (SSU) (Clock Synchronous Communication Mode)

Table 5.15 Timing Requirements of I²C bus Interface (1)

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
tSCL	SCL input cycle time		12tcyc + 600 (2)	–	–	ns
tSCLH	SCL input “H” width		3tcyc + 300 (2)	–	–	ns
tSCLL	SCL input “L” width		5tcyc + 500 (2)	–	–	ns
tsf	SCL, SDA input fall time		–	–	300	ns
tSP	SCL, SDA input spike pulse rejection time		–	–	1tcyc (2)	ns
tBUF	SDA input bus-free time		5tcyc (2)	–	–	ns
tSTAH	Start condition input hold time		3tcyc (2)	–	–	ns
tSTAS	Retransmit start condition input setup time		3tcyc (2)	–	–	ns
tSTOP	Stop condition input setup time		3tcyc (2)	–	–	ns
tSDAS	Data input setup time		1tcyc + 40 (2)	–	–	ns
tSDAH	Data input hold time		10	–	–	ns

Notes:

1. $V_{CC} = 1.8$ to 5.5 V, $V_{SS} = 0$ V and $T_{opr} = -20$ to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.
2. $1tcyc = 1/f_1(s)$

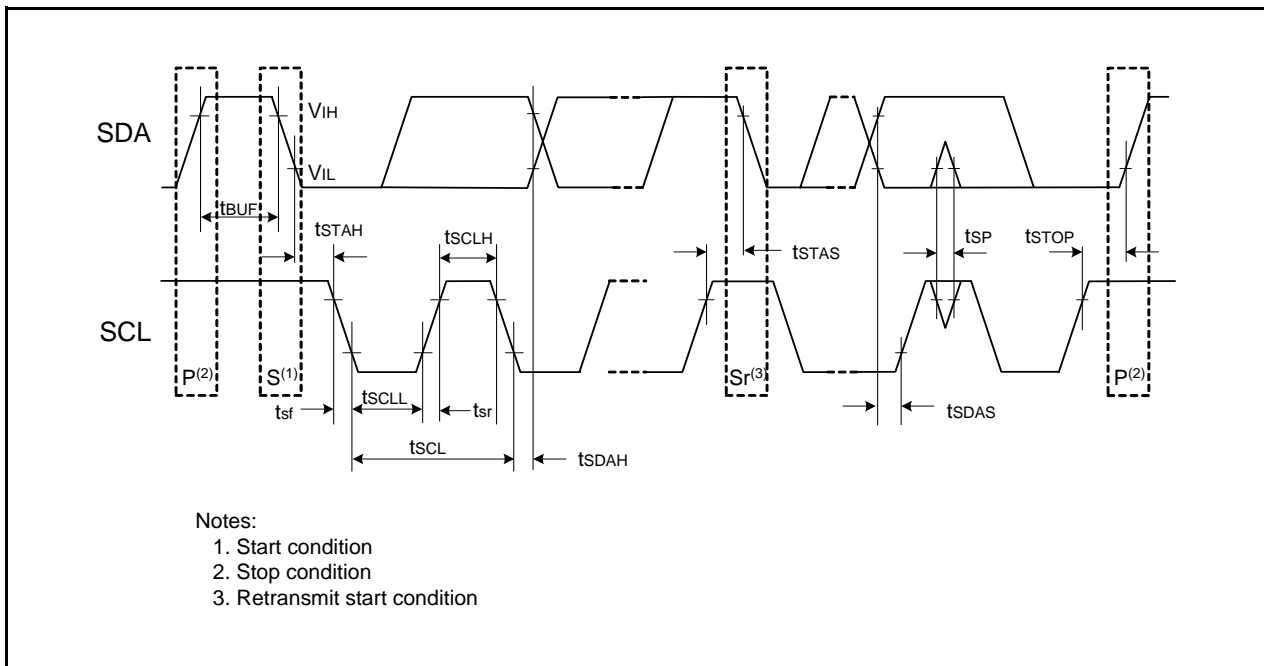
**Figure 5.7 I/O Timing of I²C bus Interface**

Table 5.16 Electrical Characteristics (1) [4.2 V ≤ Vcc ≤ 5.5 V]

Symbol	Parameter		Condition	Standard			Unit	
				Min.	Typ.	Max.		
VOH	Output "H" voltage	Other than XOUT	Drive capacity High Vcc = 5 V	IOH = -20 mA	Vcc - 2.0	-	Vcc	V
			Drive capacity Low Vcc = 5 V	IOH = -5 mA	Vcc - 2.0	-	Vcc	V
		XOUT	Vcc = 5 V	IOH = -200 μA	1.0	-	Vcc	V
VOL	Output "L" voltage	Other than XOUT	Drive capacity High Vcc = 5 V	IOL = 20 mA	-	-	2.0	V
			Drive capacity Low Vcc = 5 V	IOL = 5 mA	-	-	2.0	V
		XOUT	Vcc = 5 V	IOL = 200 μA	-	-	0.5	V
VT+ - VT-	Hysteresis	INT0, INT1, INT3, KI0, KI1, KI2, KI3, TRAIO, TRBO, TRCIOA, TRCIOB, TRCIOC, TRCIOD, TRCTRG, TRCCLK, ADTRG, RXD0, RXD2, CLK0, CLK2, SSI, SCL, SDA, SSO			0.1	1.2	-	V
		RESET			0.1	1.2	-	V
IiH	Input "H" current		VI = 5 V, Vcc = 5.0 V		-	-	5.0	μA
IiL	Input "L" current		VI = 0 V, Vcc = 5.0 V		-	-	-5.0	μA
RPULLUP	Pull-up resistance		VI = 0 V, Vcc = 5.0 V		25	50	100	kΩ
RfXIN	Feedback resistance	XIN			-	0.3	-	MΩ
RfXCIN	Feedback resistance	XCIN			-	8	-	MΩ
VRAM	RAM hold voltage		During stop mode		1.8	-	-	V

Note:

1. 4.2 V ≤ Vcc ≤ 5.5 V and Topr = -20 to 85°C (N version) / -40 to 85°C (D version), f(XIN) = 20 MHz, unless otherwise specified.

Table 5.17 Electrical Characteristics (2) [3.3 V ≤ V_{CC} ≤ 5.5 V]
(T_{opr} = −20 to 85°C (N version) / −40 to 85°C (D version), unless otherwise specified.)

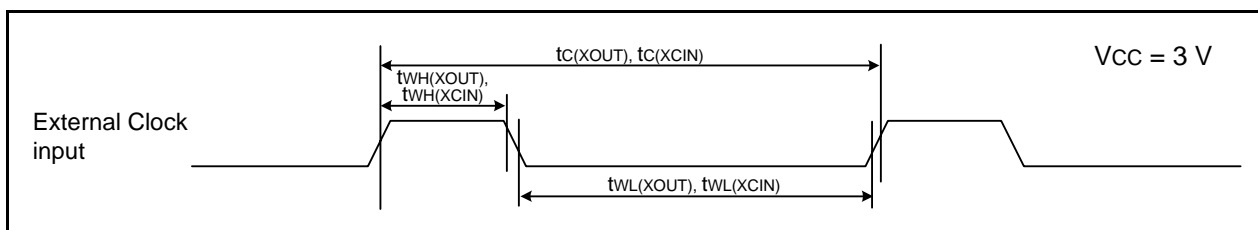
Symbol	Parameter	Condition	Standard			Unit	
			Min.	Typ.	Max.		
I _{CC}	Power supply current (V _{CC} = 3.3 to 5.5 V) Single-chip mode, output pins are open, other pins are V _{SS}	High-speed clock mode	XIN = 20 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	–	6.5	15	mA
			XIN = 16 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	–	5.3	12.5	mA
			XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	–	3.6	–	mA
			XIN = 20 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	–	3.0	–	mA
			XIN = 16 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	–	2.2	–	mA
			XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	–	1.5	–	mA
		High-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator on fOCO-F = 20 MHz Low-speed on-chip oscillator on = 125 kHz No division	–	7.0	15	mA
			XIN clock off High-speed on-chip oscillator on fOCO-F = 20 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	–	3.0	–	mA
			XIN clock off High-speed on-chip oscillator on fOCO-F = 4 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-16 MSTIIC = MSTTRD = MSTTRC = 1	–	1	–	mA
		Low-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR27 = 1, VCA20 = 0	–	90	400	μA
		Low-speed clock mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz No division FMR27 = 1, VCA20 = 0	–	85	400	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz No division Program operation on RAM Flash memory off, FMSTP = 1, VCA20 = 0	–	47	–	μA
		Wait mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock operation VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	–	15	100	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock off VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	–	4	90	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (peripheral clock off) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	–	3.5	–	μA
		Stop mode	XIN clock off, T _{opr} = 25°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	–	2.0	5.0	μA
			XIN clock off, T _{opr} = 85°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	–	5.0	–	μA

Table 5.23 Electrical Characteristics (4) [2.7 V ≤ Vcc < 3.3 V]
(Topr = −20 to 85°C (N version) / −40 to 85°C (D version), unless otherwise specified.)

Symbol	Parameter	Condition	Standard			Unit	
			Min.	Typ.	Max.		
Icc	Power supply current (Vcc = 2.7 to 3.3 V) Single-chip mode, output pins are open, other pins are Vss	High-speed clock mode	XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	−	3.5	10	mA
			XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	−	1.5	7.5	mA
		High-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator on fOCO-F = 20 MHz Low-speed on-chip oscillator on = 125 kHz No division	−	7.0	15	mA
			XIN clock off High-speed on-chip oscillator on fOCO-F = 20 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	−	3.0	−	mA
			XIN clock off High-speed on-chip oscillator on fOCO-F = 10 MHz Low-speed on-chip oscillator on = 125 kHz No division	−	4.0	−	mA
			XIN clock off High-speed on-chip oscillator on fOCO-F = 10 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	−	1.5	−	mA
			XIN clock off High-speed on-chip oscillator on fOCO-F = 4 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-16 MSTIIC = MSTTRD = MSTTRC = 1	−	1	−	mA
		Low-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR27 = 1, VCA20 = 0	−	90	390	μA
		Low-speed clock mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz No division FMR27 = 1, VCA20 = 0	−	80	400	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz No division Program operation on RAM Flash memory off, FMSTP = 1, VCA20 = 0	−	40	−	μA
		Wait mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock operation VCA27 = VCA26 = VCA25 = 0, VCA20 = 1	−	15	90	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock off VCA27 = VCA26 = VCA25 = 0, VCA20 = 1	−	4	80	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (peripheral clock off) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0, VCA20 = 1	−	3.5	−	μA
		Stop mode	XIN clock off, Topr = 25°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	−	2.0	5.0	μA
			XIN clock off, Topr = 85°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	−	5.0	−	μA

Timing requirements**(Unless Otherwise Specified: $V_{CC} = 3\text{ V}$, $V_{SS} = 0\text{ V}$ at $T_{\text{opr}} = 25^{\circ}\text{C}$)****Table 5.24 External Clock Input (XOUT, XCIN)**

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(\text{XOUT})}$	XOUT input cycle time	50	–	ns
$t_{\text{WH}(\text{XOUT})}$	XOUT input “H” width	24	–	ns
$t_{\text{WL}(\text{XOUT})}$	XOUT input “L” width	24	–	ns
$t_{c(\text{XCIN})}$	XCIN input cycle time	14	–	μs
$t_{\text{WH}(\text{XCIN})}$	XCIN input “H” width	7	–	μs
$t_{\text{WL}(\text{XCIN})}$	XCIN input “L” width	7	–	μs

**Figure 5.12 External Clock Input Timing Diagram when $V_{CC} = 3\text{ V}$** **Table 5.25 TRAI0 Input**

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(\text{TRAIO})}$	TRAIO input cycle time	300	–	ns
$t_{\text{WH}(\text{TRAIO})}$	TRAIO input “H” width	120	–	ns
$t_{\text{WL}(\text{TRAIO})}$	TRAIO input “L” width	120	–	ns

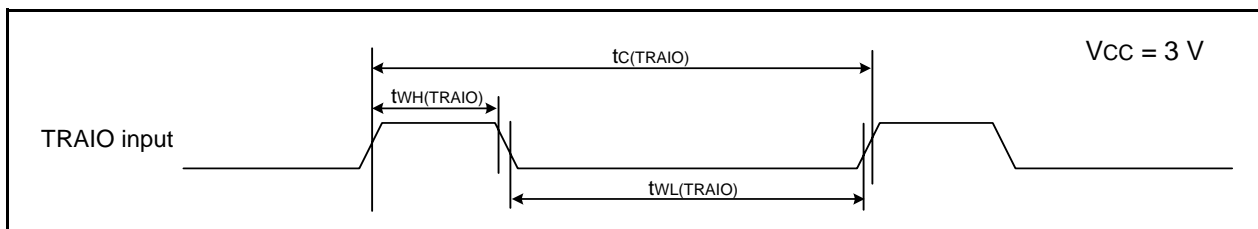
**Figure 5.13 TRAI0 Input Timing Diagram when $V_{CC} = 3\text{ V}$**

Table 5.26 Serial Interface

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(CK)}$	CLKi input cycle time	300	–	ns
$t_{w(CKH)}$	CLKi input “H” width	150	–	ns
$t_{w(CKL)}$	CLKi Input “L” width	150	–	ns
$t_{d(C-Q)}$	TXDi output delay time	–	80	ns
$t_h(C-Q)$	TXDi hold time	0	–	ns
$t_{su(D-C)}$	RXDi input setup time	70	–	ns
$t_h(C-D)$	RXDi input hold time	90	–	ns

$i = 0, 2$

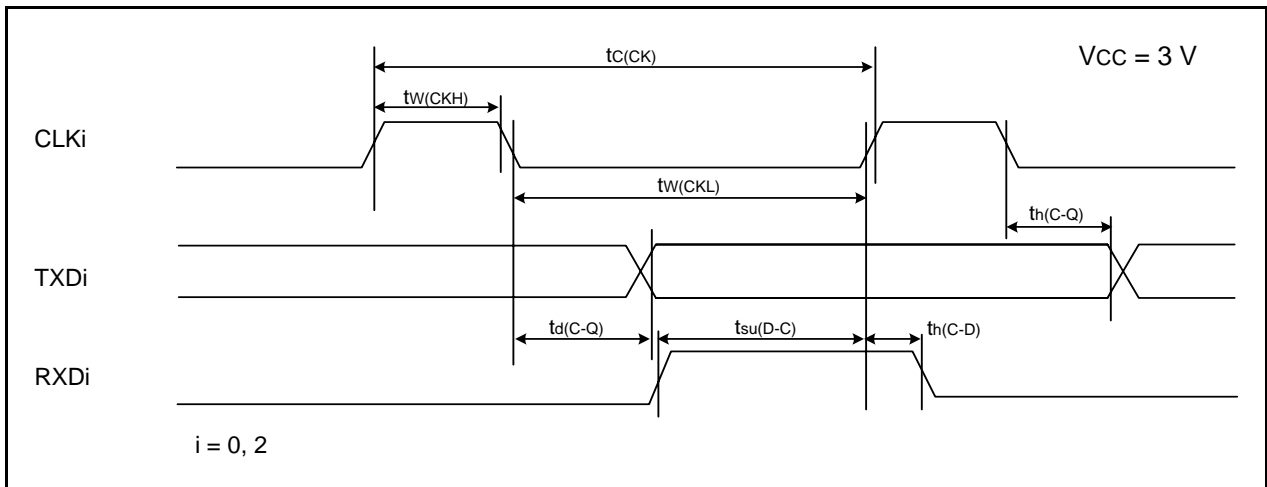


Figure 5.14 Serial Interface Timing Diagram when Vcc = 3 V

Table 5.27 External Interrupt \overline{INTi} ($i = 0, 1, 3$) Input, Key Input Interrupt \overline{Kli} ($i = 0$ to 3)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{w(INH)}$	\overline{INTi} input “H” width, \overline{Kli} input “H” width	380 (1)	–	ns
$t_{w(INL)}$	\overline{INTi} input “L” width, \overline{Kli} input “L” width	380 (2)	–	ns

Notes:

1. When selecting the digital filter by the \overline{INTi} input filter select bit, use an \overline{INTi} input HIGH width of either (1/digital filter clock frequency \times 3) or the minimum value of standard, whichever is greater.
2. When selecting the digital filter by the \overline{INTi} input filter select bit, use an \overline{INTi} input LOW width of either (1/digital filter clock frequency \times 3) or the minimum value of standard, whichever is greater.

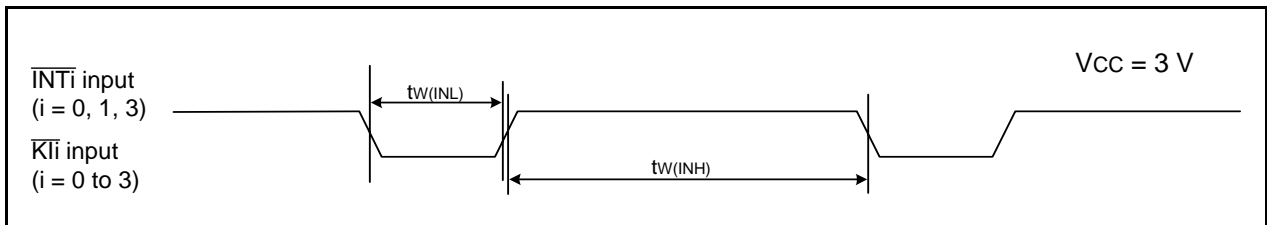


Figure 5.15 Input Timing Diagram for External Interrupt \overline{INTi} and Key Input Interrupt \overline{Kli} when Vcc = 3 V

Table 5.28 Electrical Characteristics (5) [1.8 V ≤ Vcc < 2.7 V]

Symbol	Parameter		Condition		Standard			Unit
					Min.	Typ.	Max.	
VOH	Output "H" voltage	Other than XOUT	Drive capacity High	IOH = -2 mA	Vcc - 0.5	-	Vcc	V
			Drive capacity Low	IOH = -1 mA	Vcc - 0.5	-	Vcc	V
		XOUT		IOH = -200 μA	1.0	-	Vcc	V
VOL	Output "L" voltage	Other than XOUT	Drive capacity High	IOL = 2 mA	-	-	0.5	V
			Drive capacity Low	IOL = 1 mA	-	-	0.5	V
		XOUT		IOL = 200 μA	-	-	0.5	V
VT+ - VT-	Hysteresis	INT0, INT1, INT3, KI0, KI1, KI2, KI3, TRAIO, TRBO, TRCIOA, TRCIOB, TRCIOC, TRCIOD, TRCTRG, TRCCLK, ADTRG, RXD0, RXD2, CLK0, CLK2, SSI, SCL, SDA, SSO			0.05	0.2	-	V
		RESET			0.05	0.20	-	V
IiH	Input "H" current		VI = 2.2 V, Vcc = 2.2 V		-	-	4.0	μA
IiL	Input "L" current		VI = 0 V, Vcc = 2.2 V		-	-	-4.0	μA
RPULLUP	Pull-up resistance		VI = 0 V, Vcc = 2.2 V		70	140	300	kΩ
RfXIN	Feedback resistance	XIN			-	0.3	-	MΩ
RfXCIN	Feedback resistance	XCIN			-	8	-	MΩ
V _{RAM}	RAM hold voltage		During stop mode		1.8	-	-	V

Note:

1. 1.8 V ≤ Vcc < 2.7 V at T_{opr} = -20 to 85°C (N version) / -40 to 85°C (D version), f(XIN) = 5 MHz, unless otherwise specified.

Table 5.29 Electrical Characteristics (6) [1.8 V ≤ Vcc < 2.7 V]
(Topr = −20 to 85°C (N version) / −40 to 85°C (D version), unless otherwise specified.)

Symbol	Parameter	Condition	Standard			Unit	
			Min.	Typ.	Max.		
Icc	Power supply current (Vcc = 1.8 to 2.7 V) Single-chip mode, output pins are open, other pins are Vss	High-speed clock mode	XIN = 5 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	–	2.2	–	mA
			XIN = 5 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	–	0.8	–	mA
		High-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator on fOCO-F = 5 MHz Low-speed on-chip oscillator on = 125 kHz No division	–	2.5	10	mA
			XIN clock off High-speed on-chip oscillator on fOCO-F = 5 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	–	1.7	–	mA
			XIN clock off High-speed on-chip oscillator on fOCO-F = 4 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-16 MSTIIC = MSTTRD = MSTTRC = 1	–	1	–	mA
		Low-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR27 = 1, VCA20 = 0	–	90	300	μA
		Low-speed clock mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz No division FMR27 = 1, VCA20 = 0	–	80	350	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz No division Program operation on RAM Flash memory off, FMSTP = 1, VCA20 = 0	–	40	–	μA
		Wait mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock operation VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	–	15	90	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock off VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	–	4	80	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (peripheral clock off) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	–	3.5	–	μA
		Stop mode	XIN clock off, Topr = 25°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	–	2.0	5	μA
			XIN clock off, Topr = 85°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	–	5.0	–	μA

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